

#### Pb Free Plating Product

# HER3003PT thru HER3006PT





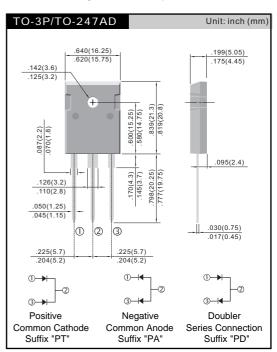
30.0 Ampere Dual Common Cathode High Efficiency Rectifier Diode

### **Features**

- Dual rectifier construction, positive center-tap
- $\diamond$ Plastic package has Underwriters Laboratory Flammability Classification 94V0
- Glass passivated chip junctions
- Special for inverter/high power motor control
- Low forward voltage, high current capability
- Low thermal resistance
- Low power loss, high efficiency
- High temperature soldering guaranteed: 260°C, 0.16"(4.06mm)from case for 10 seconds

## **Mechanical Data**

- Cases: TO-3P/TO-247AD molded plastic
- Terminals: Pure tin plated, lead free solderable per MIL-STD-750. Method 2026
- Polarity: As marked
- Mounting position: Any
- Mounting torque: 10in-lbs. Max.
- Weight: 0.2 ounce, 5.6 gram approximately



#### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

|   | SYMBOL   | HER3003PT<br>HER3003PA<br>HER3003PD | HER3005PT<br>HER3005PA<br>HER3005PD | HER3006PT<br>HER3006PA<br>HER3006PD | UNIT     |
|---|----------|-------------------------------------|-------------------------------------|-------------------------------------|----------|
| Maximum Recurrent Peak Reverse Voltage  | VRRM     | 200                                 | 400                                 | 600                                 | V        |
| Maximum RMS Voltage   | VRMS     | 140                                 | 280                                 | 420                                 | V        |
| Maximum DC Blocking Voltage   | VDC      | 200                                 | 400                                 | 600                                 | V        |
| Maximum Average Forward Rectified Current Tc=125°C  | IF(AV)   | 30.0                                |                                     |                                     | А        |
| Peak Forward Surge Current, 8.3ms single<br>Half sine-wave superimposed on rated load<br>(JEDEC method) | IFSM     | 300                                 |                                     |                                     | А        |
| Maximum Instantaneous Forward Voltage @ 15.0 A  | VF       | 0.98                                | 1.3                                 | 1.7                                 | V        |
| Maximum DC Reverse Current @Tj=25°C At Rated DC Blocking Voltage @Tj=125°C                              | lR       | 10<br>500                           |                                     |                                     | uA<br>uA |
| Maximum Reverse Recovery Time (Note 1)  | Trr      | 50                                  |                                     | 60                                  | nS       |
| Typical junction Capacitance (Note 2)   | CJ       | 175                                 |                                     | 145                                 | pF       |
| Operating Junction and Storage<br>Temperature Range   | TJ, TSTG | -55 to +150                         |                                     |                                     | °C       |

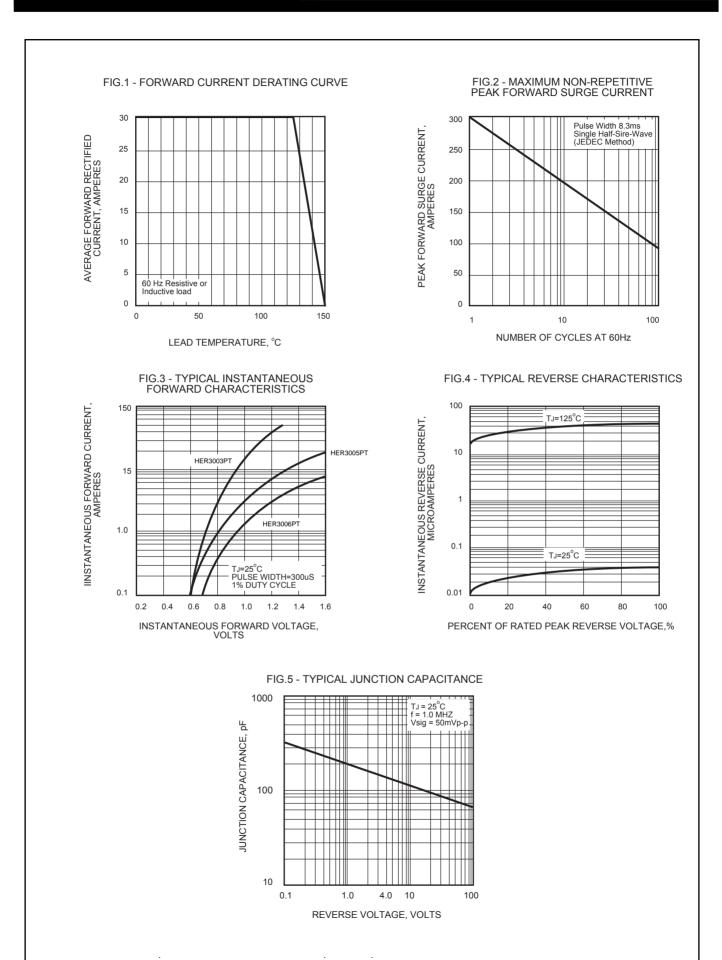
NOTES: (1) Reverse recovery test conditions IF = 0.5A IR = 1.0A Irr = 0.25A.

- (2) Thermal Resistance junction to terminal.
- (3) Measured at 1.0 MHz and applied reverse voltage of 4.0 Volts DC.

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